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## **CLAIMS:**

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1. An X-ray apparatus for high-resolution X-ray diffraction of thin layers of single crystal, comprising:

a sample stage (8) holding a sample (16) having a substantially single crystal thin layer (18) at a front face (12) with the front face (12) oriented substantially normally to a predetermined normal direction (14);

a means (4,6) for generating a collimated beam of X-rays (11) at a predetermined target location (15) on the sample stage at an angle of between 0° and 60° to the normal direction, the beam having an angular divergence at the sample stage in the range 0.01° to 0.20°; and

an X-ray detector (10) arranged laterally of the sample stage for detecting X-rays scattered by the sample (16) to a predetermined range of angles to the normal direction (14), the angles in the predetermined range being in the range from 80° to 90°,

wherein the means for generating a collimated beam of X-rays comprises an X-ray source (4) and a slit (6) between the X-ray source and the sample stage.

- 20 2. An X-ray apparatus according to claim 1 wherein the means for generating a collimated beam does not include a monochromator.
  - 3. An X-ray apparatus according to claim 1 or 2 wherein the X-ray detector (10) has a linear resolution in the normal direction (14) of less than 0.002 times the distance from the X-ray detector to the predetermined target location.
  - 4. X-ray apparatus according to claim 1, 2 or 3 wherein the X-ray source (3) has a dimension of no more than 0.2mm in the direction normal to the beam in the plane containing the normal, the incident beam and the scattered X-rays.

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- 5. An X-ray apparatus according to any preceding claim wherein the X-ray detector (10) is an elongate X-ray detector extending in a direction parallel to the normal direction (14) for detecting in parallel X-rays diffracted by the sample as a function of distance along the normal direction and hence over a predetermined range of angles to the normal direction.
- 6. An X-ray apparatus according to any preceding claim wherein the position sensitive X-ray detector (10) is a solid state detector.
- 7. An X-ray apparatus according to any preceding claim wherein the substantially single crystal thin layer (18) is a semiconductor layer.
  - 8. Use of an X-ray apparatus according to any preceding claim to measure the sample (16) the sample (16) being mounted on the sample stage (8) and oriented to diffract the collimated X-ray beam (11) onto the position sensitive X-ray detector (10).
  - A method of high-resolution X-ray diffraction; comprising: providing a sample stage and an X-ray detector located laterally of the sample stage;

mounting a sample having a substantially single crystal thin layer material extending in a plane on the sample stage;

directing an incident collimated beam of x-rays created without a monochromator onto the sample at an angle of 0° to 60° to the normal to the plane; and

measuring with the X-ray detector the X-rays diffracted by the sample to a range of angles in the range 80° to 90° to the normal to the plane.

10. A method according to claim 9 wherein the incident beam has an angular divergence in the range 0.01° to 0.20°.





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- 11. A method according to claim 9 or 10 wherein the incident beam of X-rays is in a direction from 0° to 40° to the normal to the plane.
- 12. A method according to any of claims 9 to 11 wherein the step of measuring the X-rays diffracted by the sample (16) includes recording the intensity of X-rays incident on the detector (10) simultaneously at a number of locations along the length of the detector.